

BAW56

Rev.E May.-2021

DATA SHEET

/ Descriptions

SOT-23

Silicon Diode in a SOT-23 Plastic Package.

/ Features

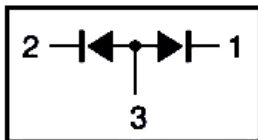
450mA

Small package, double diode, high switching speed, high repetitive peak reverse voltage, repetitive peak forward current up to 450mA. HF Product.

/ Applications

High-speed switching in thick and thin-film circuits..

/ Equivalent Circuit



/ Pinning



PIN: See Equivalent Circuit.

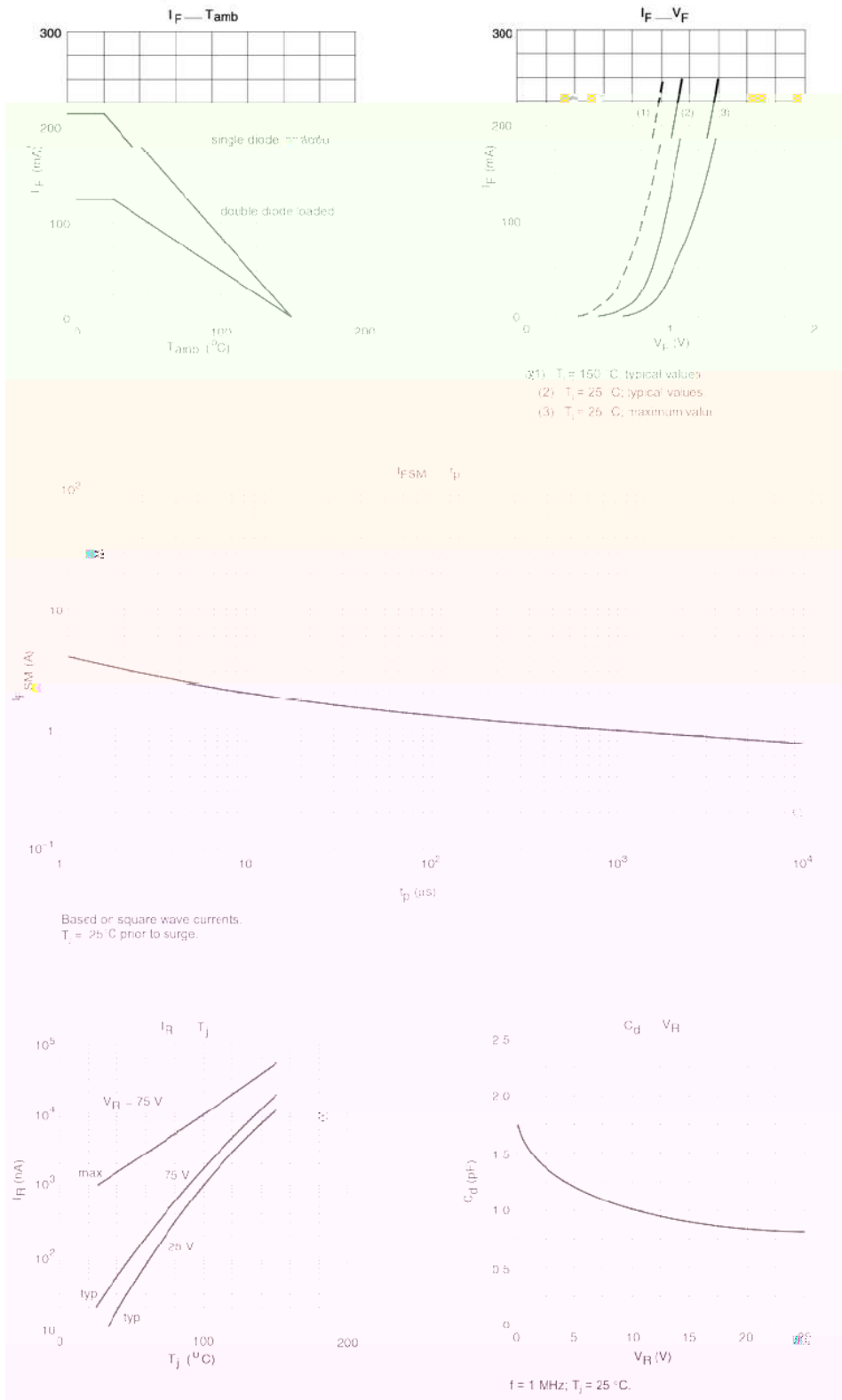
/ hFE Classifications & Marking

Marking	HA1
---------	-----

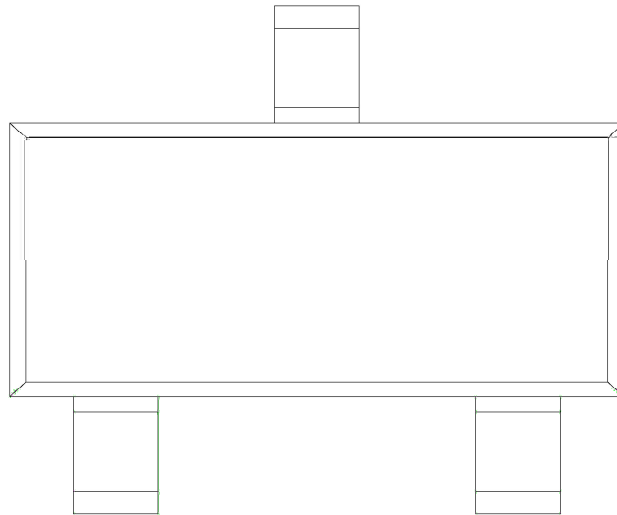
Parameter	Symbol	Rating	Unit
Repetitive Reverse Voltage	V_{RRM}	85	V
Continuous Reverse Voltage	V_R	75	V
Average Rectified Forward Current	$I_{F(\text{single diode loaded})}$	215	mA
	$I_{F(\text{double diode loaded})}$	125	mA
Repetitive Peak Forward Current	I_{FRM}	450	mA
Non-repetitive Peak Forward Surge Current	$I_{FSM(1)(t=1\mu S)}$	4.0	A
	$I_{FSM(2)(t=1mS)}$	1.0	A
	$I_{FSM(3)(t=1S)}$	0.5	A
Power Dissipation	P_{tot}	250	mW

Junctioi

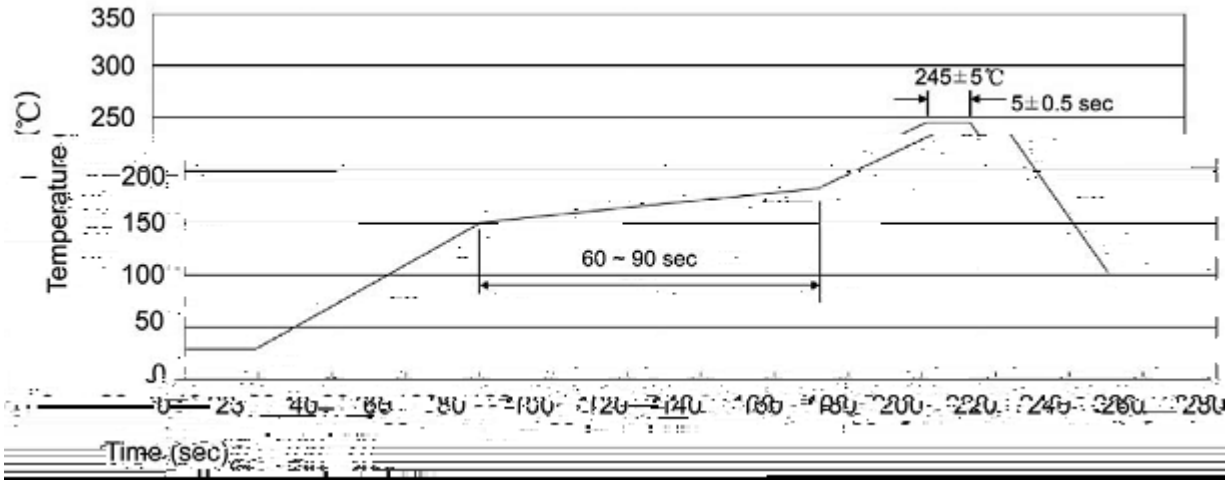
/ Electrical Characteristic Curve



/ Marking Instructions



() / Temperature Profile for IR Reflow Soldering(Pb-Free)



Note:

- | | | | | | |
|---|-------|-----|-----------|--------|---|
| 1 | 25 | 150 | 60 | 90sec; | 1.Preheating:25~150 , Time:60~90sec. |
| 2 | 245±5 | | 5±0.5sec; | | 2.Peak Temp.:245±5 , Duration:5±0.5sec. |
| 3 | | 2 | 10 | /sec. | 3. Cooling Speed: 2~10 /sec. |

/ Resistance to Soldering Heat Test Conditions

260±5 10±1 sec. Temp.:260±5°C Time:10±1 sec

/ Packaging SPEC.

/ REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)	
	只卷盘	卷盘盒	只盒	盒箱	只箱	盒	箱